

Supplementary Materials

Sensitivity Enhanced Plasmonic Biosensor Using Bi₂Se₃-

Graphene Heterostructures: A Theoretical Analysis

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Supplementary Figures

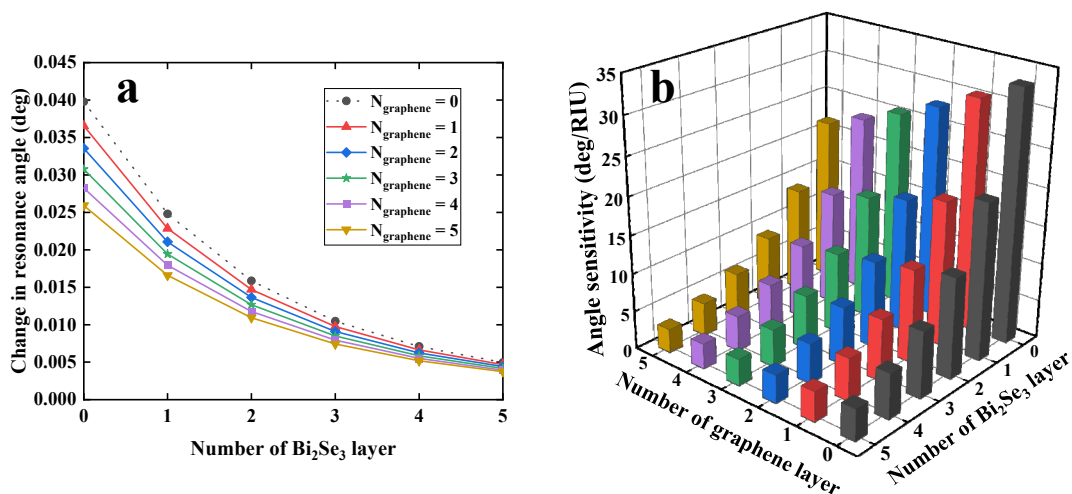


Figure S1 Change in resonance angle (a) and obtained angle sensitivity (b) by varying the number of Bi_2Se_3 QLs (0-5) and graphene (0-5) for a defined RI variation of 0.0012 RIU.

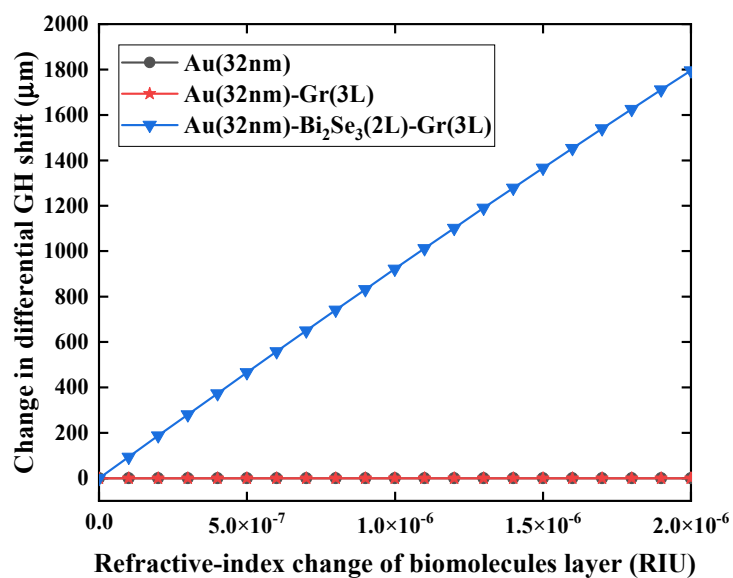


Figure S2 Comparison of SPR sensing performances generated by 32nm Au thin film, 3-layer graphene coated on 32 nm Au thin film, and 32 nm Au film deposited with two-QLs Bi_2Se_3 and three-layer graphene for a tiny RI variation (as low as 10^{-6} RIU).